NSN 5961-01-243-3505

Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-243-3505 **Inclosure Material:** Metal **Overall Length:** 0.247 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.219 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 collector to emitter voltage, dc and 5.0 emitter to collector voltage, dc **Current Rating Per Characteristic:** 7.00 milliamperes collector cutoff current, dc, emitter open and 100.00 microamperes repetitive peak forward current peak **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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